



60V P-Channel Enhancement Mode MOSFET

Voltage

-60 V

Current

-1.9A

Features

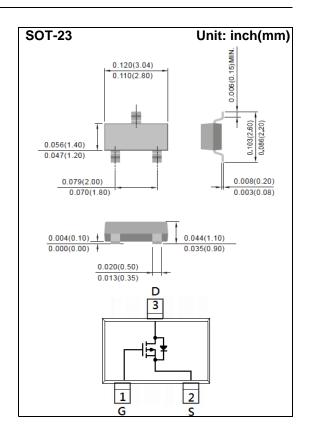
- $R_{DS(ON)}$, V_{GS} @-10V, I_{D} @-1.9A<170m Ω
- $R_{DS(ON)}$, V_{GS} @-4.5V, I_D @-1.5A<220m Ω
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

• Case: SOT-23 Package

• Terminals: Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.0003 ounces, 0.0084 grams



Maximum Ratings and Thermal Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNITS		
Drain-Source Voltage		V _{DS}	-60	V	
Gate-Source Voltage		V_{GS}	<u>+</u> 20		
Continuous Drain Current (Note 4)	T _A =25°C	l _D	-1.9		
	T _A =70°C		-1.5	Α	
Pulsed Drain Current (Note 1)		I _{DM}	-7.6		
Power Dissipation	T _A =25°C	P _D	1.25		
	T _A =70°C		0.8	W	
Single Pulse Avalanche Energy (Note 6)		E _{AS}	32	mJ	
Operating Junction and Storage Temperature Range		T_{J} , T_{STG}	-55~150	°C	
Typical Thermal Resistance - Junction to Ambient (Note 4,5)		$R_{\theta JA}$	100	°C/W	





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS		
Static								
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =-250uA	-60	-	-	.,		
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=-250uA$	250uA -1 -1.88 -2.5	V				
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-10V, I _D =-1.9A	-	140	170	mΩ		
		V _{GS} =-4.5V, I _D =-1.5A	-	190	220			
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-60V, V _{GS} =0V	-	-	-1	uA		
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 12V, V _{DS} =0V	-	-	<u>+</u> 100	nA		
Dynamic (Note 7)								
Total Gate Charge	Q_g	V _{DS} =-30V, I _D =-1.9A, V _{GS} =-10V ^(Note 2,3)	-	8.3	-	nC		
Gate-Source Charge	Q_{gs}		-	1.8	-			
Gate-Drain Charge	Q_gd		-	1.6	-			
Input Capacitance	Ciss	V _{DS} =-30V, V _{GS} =0V, f=1.0MHZ	-	430	-	pF		
Output Capacitance	Coss		-	33	-			
Reverse Transfer Capacitance	Crss		-	29	-			
Turn-On Delay Time	td _(on)	V_{DD} =-30V, I_{D} =-1A, V_{GS} =-10V, R_{G} =6 Ω (Note 2,3)	-	5.1	-	ns		
Turn-On Rise Time	tr		-	20	-			
Turn-Off Delay Time	td _(off)		-	36	-			
Turn-Off Fall Time	tf		-	11	-			
Drain-Source Diode								
Maximum Continuous Drain-Source	I _S		-	-	-1.5	А		
Diode Forward Current (Note 3)	'5							
Diode Forward Voltage	V_{SD}	I _S =-1A, V _{GS} =0V	-	-0.78	-1	V		

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature $T_{J(MAX)}$ =150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
- 4. The maximum current rating is package limited.
- 5. Roja is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. The test condition is L=1mH, I_{AS} =-8A, V_{DD} =-25V, V_{GS} =-10V.
- 7. Guaranteed by design, not subject to production testing.





TYPICAL CHARACTERISTIC CURVES

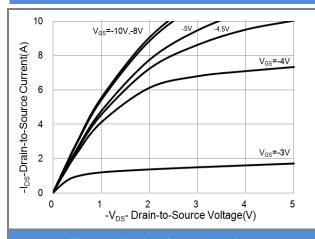


Fig.1 On-Region Characteristics

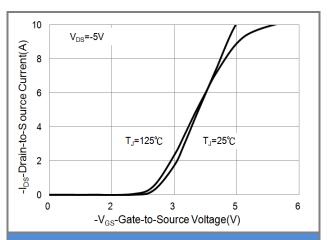


Fig.2 Transfer Characteristics

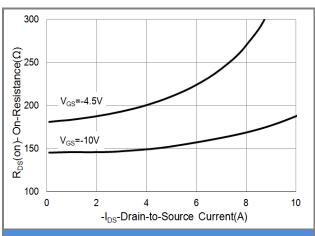


Fig.3 On-Resistance vs. Drain Current

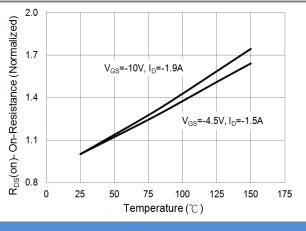


Fig.4 On-Resistance vs. Junction temperature

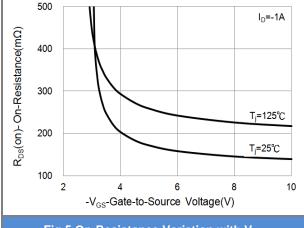


Fig.5 On-Resistance Variation with V_{GS}

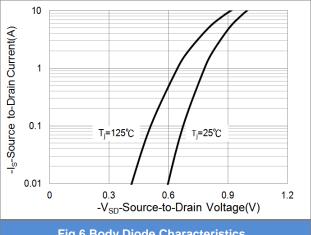


Fig.6 Body Diode Characteristics





TYPICAL CHARACTERISTIC CURVES

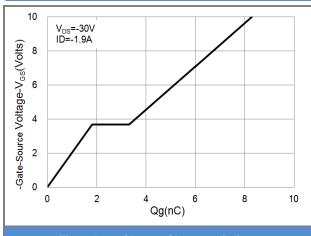


Fig.7 Gate-Charge Characteristics

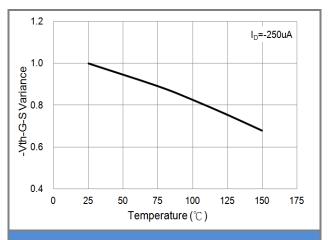


Fig.8 Threshold Voltage Variation with Temperature

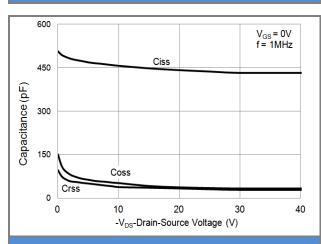


Fig.9 Capacitance vs. Drain-Source Voltage

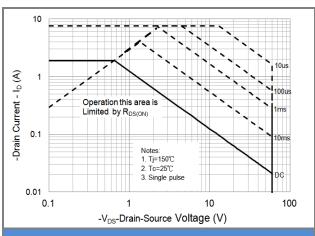
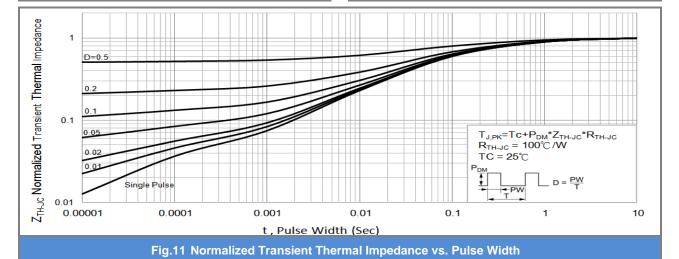


Fig.10 Maximum Safe Operating Area



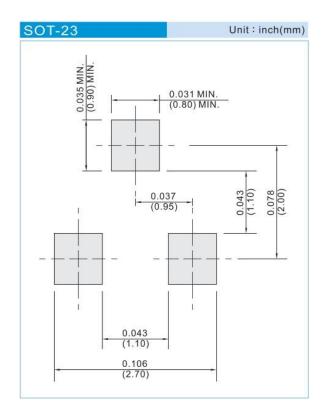




Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJA3461-AU_R1_000A1	SOT-23	3K pcs / 7" reel	A61	Halogen free

Packaging Information & Mounting Pad Layout







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